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What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Obsolete
Core Processor	ARM® Cortex®-M4
Core Size	32-Bit Single-Core
Speed	72MHz
Connectivity	CANbus, I ² C, IrDA, LINbus, SPI, UART/USART, USB
Peripherals	DMA, I ² S, POR, PWM, WDT
Number of I/O	84
Program Memory Size	128KB (128K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	24K x 8
Voltage - Supply (Vcc/Vdd)	2V ~ 3.6V
Data Converters	A/D 1x12b, 1x16b; D/A 1x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	100-LQFP
Supplier Device Package	100-LQFP (14x14)
Purchase URL	https://www.e-xfl.com/product-detail/stmicroelectronics/stm32f372vbt6

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Table 2. Device overview

Peripheral		STM32F372Cx			STM32F372Rx			STM32F372Vx			STM32F373Cx			STM32F373Rx			STM32F373Vx		
Flash (Kbytes)		64	128	256	64	128	256	64	128	256	64	128	256	64	128	256	64	128	256
SRAM (Kbytes)		16	24	32	16	24	32	16	24	32	16	24	32	16	24	32	16	24	32
Timers	General purpose	9 (16-bit) 2 (32 bit)									9 (16-bit) 2 (32 bit)								
	Basic	3 (16-bit)									3 (16-bit)								
Comm. interfaces	SPI/I2S	3									3								
	I ² C	2									2								
	USART	3									3								
	CAN	1									1								
	USB	1									1								
GPIOs	Normal I/Os (TC, TTa)	36			52			84			36			52			84		
	5 volts Tolerant I/Os (FT, Ftf)	20			28			45			20			28			45		
12-bit ADCs		1									1								
16-bit ADCs Sigma- Delta		1 (SDADC1)									3								
12-bit DACs outputs		1 (DAC2)									3								
Analog comparator		1 (COMP1)									2								
Capacitive sensing channels		14			17			24			14			17			24		
Max. CPU frequency		72 MHz									72 MHz								
Main operating voltage		2.0 to 3.6 V									2.0 to 3.6 V								
16-bit SDADC operating voltage		2.2 to 3.6 V									2.2 to 3.6 V								
Operating temperature		Ambient operating temperature: –40 to 85 °C / –40 to 105 °C Junction temperature: –40 to 125 °C									Ambient operating temperature: –40 to 85 °C / –40 to 105 °C Junction temperature: –40 to 125 °C								
Packages		LQFP48			LQFP64			LQFP100, UFBGA100 ⁽¹⁾			LQFP48			LQFP64			LQFP100, UFBGA100 ⁽¹⁾		

1. UFBGA100 package available on 256-KB versions only.

3 Functional overview

3.1 ARM® Cortex™-M4F core with embedded Flash and SRAM

The ARM Cortex-M4F processor is the latest generation of ARM processors for embedded systems. It was developed to provide a low-cost platform that meets the needs of MCU implementation, with a reduced pin count and low-power consumption, while delivering outstanding computational performance and an advanced response to interrupts.

The ARM Cortex-M4F 32-bit RISC processor features exceptional code-efficiency, delivering the high-performance expected from an ARM core in the memory size usually associated with 8- and 16-bit devices.

The processor supports a set of DSP instructions which allow efficient signal processing and complex algorithm execution.

Its single precision FPU speeds up software development by using metalanguage development tools, while avoiding saturation.

With its embedded ARM core, the STM32F37x family is compatible with all ARM tools and software.

Figure 1 shows the general block diagram of the STM32F37x family.

3.2 Memory protection unit

The memory protection unit (MPU) is used to separate the processing of tasks from the data protection. The MPU can manage up to 8 protection areas that can all be further divided up into 8 subareas. The protection area sizes are between 32 bytes and the whole 4 gigabytes of addressable memory.

The memory protection unit is especially helpful for applications where some critical or certified code has to be protected against the misbehavior of other tasks. It is usually managed by an RTOS (real-time operating system). If a program accesses a memory location that is prohibited by the MPU, the RTOS can detect it and take action. In an RTOS environment, the kernel can dynamically update the MPU area setting, based on the process to be executed.

The MPU is optional and can be bypassed for applications that do not need it.

The Cortex-M4F processor is a high performance 32-bit processor designed for the microcontroller market. It offers significant benefits to developers, including:

- Outstanding processing performance combined with fast interrupt handling
- Enhanced system debug with extensive breakpoint and trace capabilities
- Efficient processor core, system and memories
- Ultralow power consumption with integrated sleep modes
- Platform security robustness with optional integrated memory protection unit (MPU).

With its embedded ARM core, the STM32F37x devices are compatible with all ARM development tools and software.

The RTC clock sources can be:

- A 32.768 kHz external crystal
- A resonator or oscillator
- The internal low-power RC oscillator (typical frequency of 40 kHz)
- The high-speed external clock divided by 32

3.19 Inter-integrated circuit interface (I²C)

Up to two I²C bus interfaces can operate in multimaster and slave modes. They can support standard (up to 100 kHz), fast (up to 400 kHz) and fast mode + (up to 1 MHz) modes with 20 mA output drive. They support 7-bit and 10-bit addressing modes, multiple 7-bit slave addresses (2 addresses, 1 with configurable mask). They also include programmable analog and digital noise filters.

Table 6. Comparison of I²C analog and digital filters

	Analog filter	Digital filter
Pulse width of suppressed spikes	≥ 50 ns	Programmable length from 1 to 15 I ² C peripheral clocks
Benefits	Available in Stop mode	1. Extra filtering capability vs. standard requirements. 2. Stable length
Drawbacks	Variations depending on temperature, voltage, process	Wakeup from Stop on address match is not available when digital filter is enabled

In addition, they provide hardware support for SMBUS 2.0 and PMBUS 1.1: ARP capability, Host notify protocol, hardware CRC (PEC) generation/verification, timeout verifications and ALERT protocol management. They also have a clock domain independent from the CPU clock, allowing the application to wake up the MCU from Stop mode on address match.

The I²C interfaces can be served by the DMA controller

Refer to [Table 7](#) for the differences between I2C1 and I2C2.

Table 7. STM32F37x I²C implementation

I ² C features ⁽¹⁾	I2C1	I2C2
7-bit addressing mode	X	X
10-bit addressing mode	X	X
Standard mode (up to 100 kbit/s)	X	X
Fast mode (up to 400 kbit/s)	X	X
Fast Mode Plus with 20mA output drive I/Os (up to 1 Mbit/s)	X	X
Independent clock	X	X
SMBus	X	X
Wakeup from STOP	X	X

1. X = supported.

4 Pinouts and pin description

Figure 2. STM32F37x LQFP48 pinout

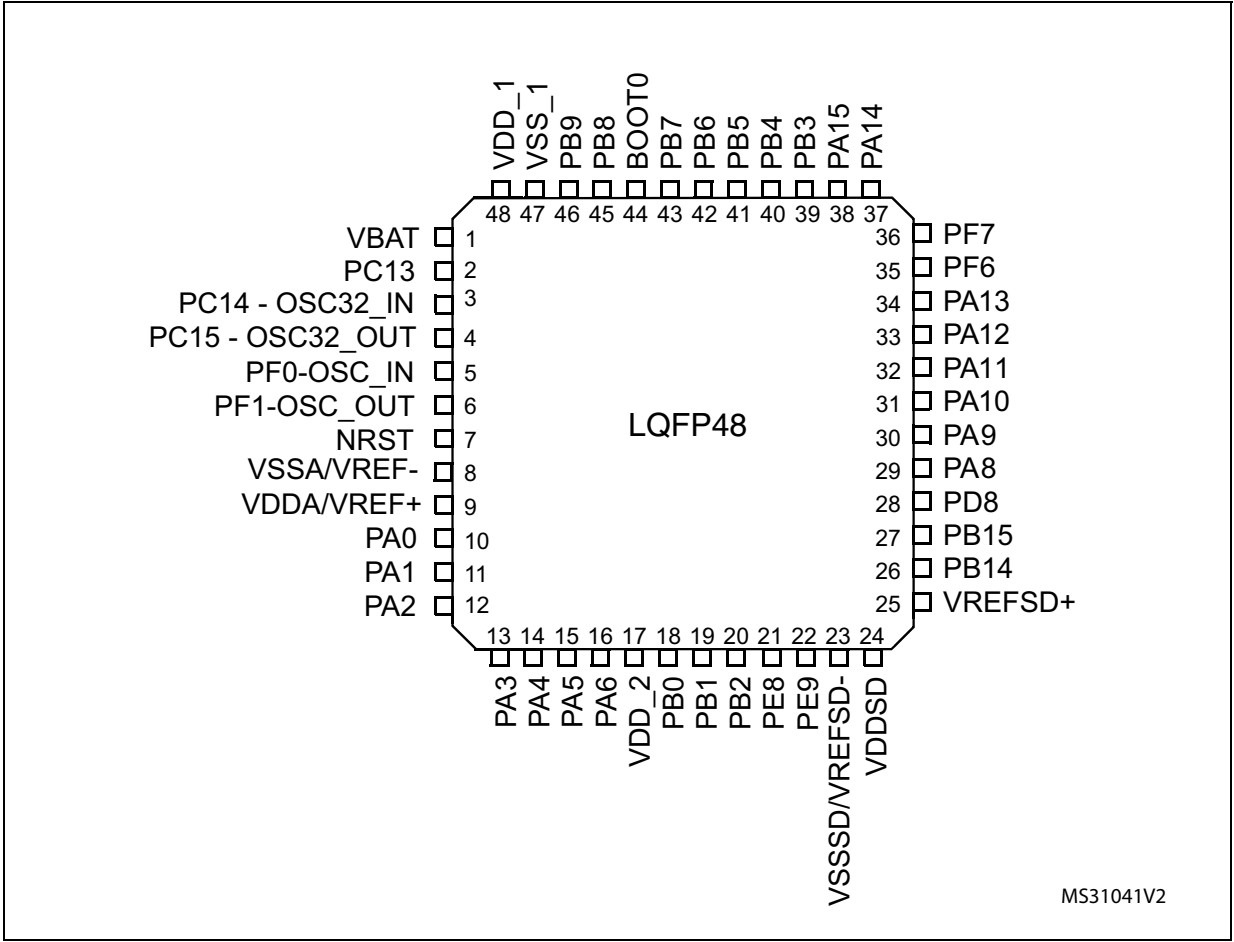


Table 10. Legend/abbreviations used in the pinout table

Name		Abbreviation	Definition
Pin name		Unless otherwise specified in brackets below the pin name, the pin function during and after reset is the same as the actual pin name	
Pin type	S	Supply pin	
	I	Input only pin	
	I/O	Input / output pin	
I/O structure	FT	5 V tolerant I/O	
	FTf	5 V tolerant I/O, FM+ capable	
	TTa	3.3 V tolerant I/O directly connected to ADC	
	TC	Standard 3.3 V I/O	
	B	Dedicated BOOT0 pin	
	RST	Bidirectional reset pin with embedded weak pull-up resistor	
Notes		Unless otherwise specified by a note, all I/Os are set as floating inputs during and after reset	
Pin functions	Alternate functions	Functions selected through GPIOx_AFR registers	
	Additional functions	Functions directly selected/enabled through peripheral registers	

Table 11. STM32F37x pin definitions

Pin numbers				Pin name (function after reset)	Pin type	I/O structure	Notes	Pin functions	
LQFP100	BGA100	LQFP64	LQFP48					Alternate function	Additional functions
1	B2			PE2	I/O	FT	(1)	TSC_G7_IO1, TRACECLK	
2	A1			PE3	I/O	FT	(1)	TSC_G7_IO2, TRACED0	
3	B1			PE4	I/O	FT	(1)	TSC_G7_IO3, TRACED1	
4	C2			PE5	I/O	FT	(1)	TSC_G7_IO4, TRACED2	
5	D2			PE6	I/O	FT	(1)	TRACED3	WKUP3, RTC_TAMPER3
6	E2	1	1	VBAT	S			Backup power supply	
7	C1	2	2	PC13	I/O	TC			WKUP2_ALARM_OUT, CALIB_OUT_TIMESTAMP, RTC_TAMPER1
8	D1	3	3	PC14 - OSC32_IN	I/O	TC			OSC32_IN
9	E1	4	4	PC15 - OSC32_OUT	I/O	TC			OSC32_OUT
10	F2			PF9	I/O	FT	(1)	TIM14_CH1	

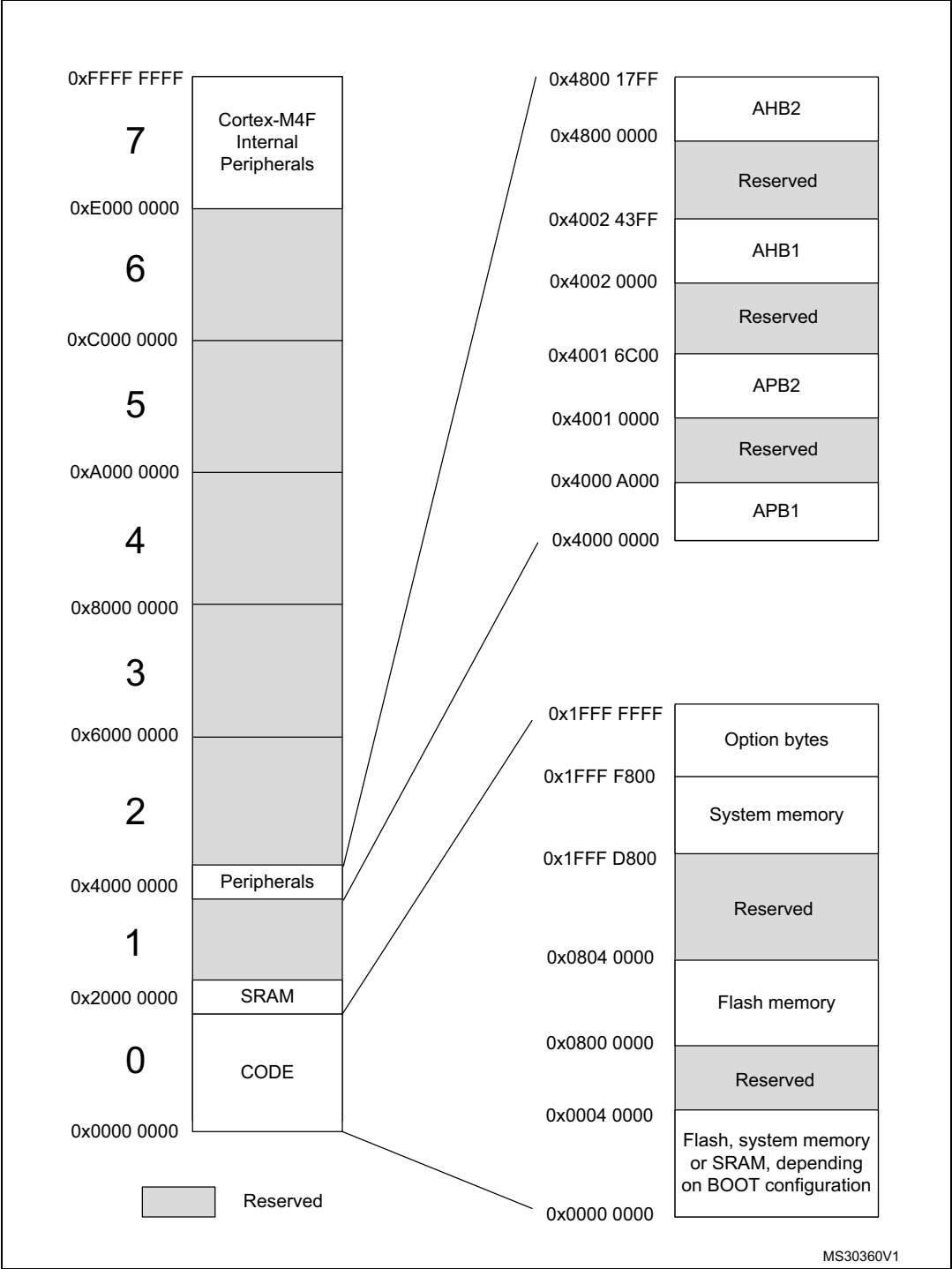
Table 11. STM32F37x pin definitions (continued)

Pin numbers				Pin name (function after reset)	Pin type	I/O structure	Notes	Pin functions	
LQFP100	BGA100	LQFP64	LQFP48					Alternate function	Additional functions
90	A7	56	40	PB4	I/O	FT		SPI1_MISO/I2S1_MCK, SPI3_MISO/I2S3_MCK, USART2_RX, TIM16_CH1, TIM3_CH1, TIM17_BKIN, TIM15_CH1N, TSC_G5_IO2, JNTRST	
91	C5	57	41	PB5	I/O	FT		SPI1_MOSI/I2S1_SD, SPI3_MOSI/I2S3_SD, I2C1_SMBAL, USART2_CK, TIM16_BKIN, TIM3_CH2, TIM17_CH1, TIM19_ETR	
92	B5	58	42	PB6	I/O	FTf		I2C1_SCL, USART1_TX, TIM16_CH1N, TIM3_CH3, TIM4_CH1, TIM19_CH1, TIM15_CH1, TSC_G5_IO3	
93	B4	59	43	PB7	I/O	FTf		I2C1_SDA, USART1_RX, TIM17_CH1N, TIM3_CH4, TIM4_CH2, TIM19_CH2, TIM15_CH2, TSC_G5_IO4	
94	A4	60	44	BOOT0	I	B		Boot memory selection	
95	A3	61	45	PB8	I/O	FTf		SPI2_SCK/I2S2_CK, I2C1_SCL, USART3_TX, CAN_RX, CEC, TIM16_CH1, TIM4_CH3, TIM19_CH3, COMP1_OUT, TSC_SYNC	
96	B3	62	46	PB9	I/O	FTf		SPI2_NSS/I2S2_WS, I2C1_SDA, USART3_RX, CAN_TX, IR_OUT, TIM17_CH1, TIM4_CH4, TIM19_CH4, COMP2_OUT	
97	C3			PE0	I/O	FT	(1)	USART1_TX, TIM4_ETR	
98	A2			PE1	I/O	FT	(1)	USART1_RX	
99	D3	63	47	VSS_1	S			Ground	
100	C4	64	48	VDD_1	S			Digital power supply	

1. When using the small packages (48 and 64 pin packages), the GPIO pins which are not present on these packages, must not be configured in analog mode.
2. these pins are powered by VDDSD12.
3. these pins are powered by VDDSD3.

5 Memory mapping

Figure 6. STM32F37x memory map



6.3.5 Supply current characteristics

The current consumption is a function of several parameters and factors such as the operating voltage, ambient temperature, I/O pin loading, device software configuration, operating frequencies, I/O pin switching rate, program location in memory and executed binary code.

The current consumption is measured as described in [Figure 10: Current consumption measurement scheme](#).

All Run-mode current consumption measurements given in this section are performed with a reduced code that gives a consumption equivalent to CoreMark code.

Typical and maximum current consumption

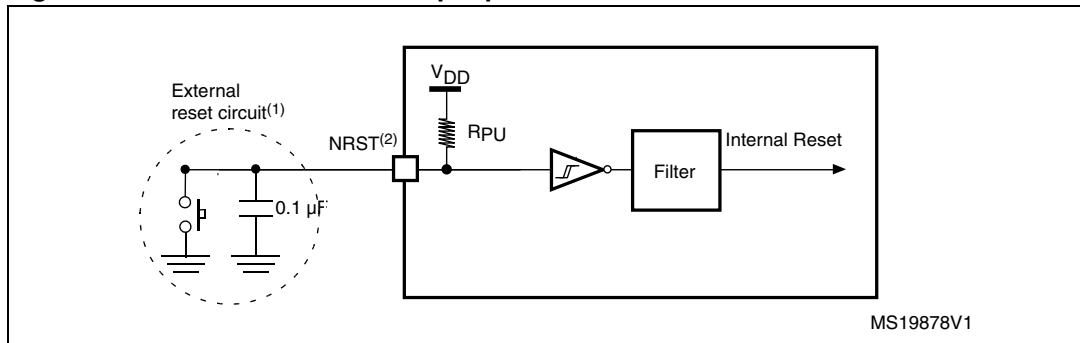
The MCU is placed under the following conditions:

- All I/O pins are in input mode with a static value at V_{DD} or V_{SS} (no load)
- All peripherals are disabled except when explicitly mentioned
- The Flash memory access time is adjusted to the f_{HCLK} frequency (0 wait state from 0 to 24 MHz, 1 wait state from 24 to 48 MHz and 2 wait states from 48 MHz to 72 MHz)
- Prefetch in ON (reminder: this bit must be set before clock setting and bus prescaling)
- When the peripherals are enabled $f_{APB1} = f_{AHB}/2$, $f_{APB2} = f_{AHB}$
- When $f_{HCLK} > 8$ MHz PLL is ON and PLL inputs is equal to $HSI/2 = 4$ MHz (if internal clock is used) or HSE = 8 MHz (if HSE bypass mode is used)

The parameters given in [Table 28](#) to [Table 34](#) are derived from tests performed under ambient temperature and supply voltage conditions summarized in [Table 22](#).

Table 28. Typical and maximum current consumption from V_{DD} supply at $V_{DD} = 3.6$ V

Symbol	Parameter	Conditions	f _{HCLK}	All peripherals enabled				All peripherals disabled				Unit
				Typ	Max @ T _A ⁽¹⁾			Typ	Max @ T _A ⁽¹⁾			
					25 °C	85 °C	105 °C		25 °C	85 °C	105 °C	
I _{DD}	Supply current in Run mode, code executing from Flash	HSE bypass, PLL on	72 MHz	63.1	70.7	71.5	73.4	29.2	31.1	31.7	34.2	mA
			64 MHz	56.3	63.3	64.1	64.9	26.1	27.8	28.4	30.4	
			48 MHz	42.5	48.5	48.0	50.1	19.9	22.6	21.9	23.1	
			32 MHz	28.8	31.4	32.2	34.3	13.1	16.1	14.9	16.2	
			24 MHz	21.9	24.4	24.4	25.8	10.1	10.9	11.9	12.4	
		HSE bypass, PLL off	8 MHz	7.3	8.0	9.3	9.3	3.7	4.1	4.4	5.0	
			1 MHz	1.1	1.5	1.8	2.3	0.8	1.1	1.4	1.9	
		HSI clock, PLL on	64 MHz	51.7	57.7	58.0	60.4	25.8	27.6	28.1	30.1	
			48 MHz	38.6	45.9	43.5	46.9	19.8	21.9	21.7	22.8	
			32 MHz	26.4	31.1	29.7	31.9	13.1	15.7	14.8	16.2	
			24 MHz	20.3	22.6	22.6	23.7	6.9	7.5	8.1	8.8	
		HSI clock, PLL off	8 MHz	7.0	7.6	8.8	8.8	3.7	4.1	4.4	5.0	

Figure 22. Recommended NRST pin protection

1. The reset network protects the device against parasitic resets.
2. The user must ensure that the level on the NRST pin can go below the $V_{IL(NRST)}$ max level specified in [Table 55](#). Otherwise the reset will not be taken into account by the device.

6.3.16 Communications interfaces

I²C interface characteristics

Unless otherwise specified, the parameters given in [Table 56](#) are derived from tests performed under ambient temperature, f_{PCLK1} frequency and V_{DD} supply voltage conditions summarized in [Table 22](#).

The I²C interface meets the requirements of the standard I²C communication protocol with the following restrictions: the I/O pins SDA and SCL are mapped to are not “true” open-drain. When configured as open-drain, the PMOS connected between the I/O pin and V_{DD} is disabled, but is still present.

The I²C characteristics are described in [Table 56](#). Refer also to [Section 6.3.14: I/O port characteristics](#) for more details on the input/output alternate function characteristics (SDA and SCL).

Table 56. I²C characteristics⁽¹⁾

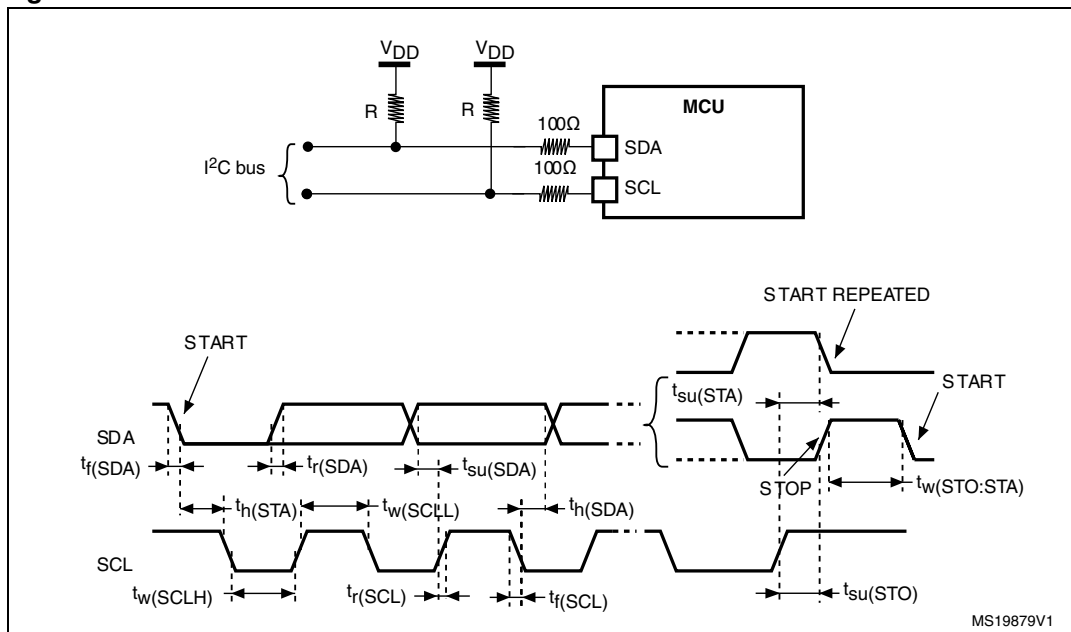
Symbol	Parameter	Standard mode		Fast mode		Fast mode Plus		Unit
		Min	Max	Min	Max	Min	Max	
$t_{w(SCLL)}$	SCL clock low time	4.7		1.3		0.5		μs
$t_{w(SCLH)}$	SCL clock high time	4.0		0.6		0.26		
$t_{su(SDA)}$	SDA setup time	250		100		50		ns
$t_h(SDA)$	SDA data hold time	0 ⁽²⁾	3450 ⁽³⁾	0 ⁽²⁾	900 ⁽³⁾	0 ⁽⁴⁾	450 ⁽³⁾	
$t_r(SDA)$ $t_r(SCL)$	SDA and SCL rise time		1000		300		120	
$t_f(SDA)$ $t_f(SCL)$	SDA and SCL fall time		300		300		120	
$t_h(STA)$	Start condition hold time	4.0		0.6		0.26		μs
$t_{su(STA)}$	Repeated Start condition setup time	4.7		0.6		0.26		
$t_{su(STO)}$	Stop condition setup time	4.0		0.6		0.26		μs
$t_{w(STO:STA)}$	Stop to Start condition time (bus free)	4.7		1.3		0.5		μs
C_b	Capacitive load for each bus line		400		400		550	pF

1. The I²C characteristics are the requirements from I²C bus specification rev03. They are guaranteed by design when I2Cx_TIMING register is correctly programmed (Refer to reference manual). These characteristics are not tested in production.
2. The device must internally provide a hold time of at least 300ns for the SDA signal in order to bridge the undefined region of the falling edge of SCL.
3. The maximum Data hold time has only to be met if the interface does not stretch the low period of SCL signal.
4. The device must internally provide a hold time of at least 120ns for the SDA signal in order to bridge the undefined region of the falling edge of SCL.

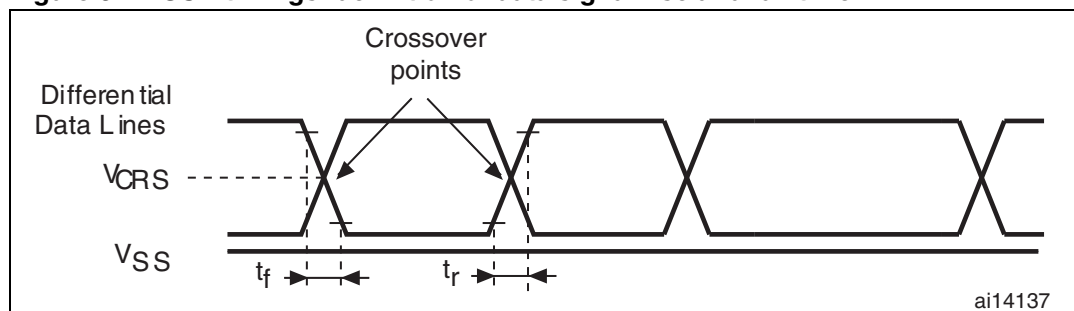
Table 57. I²C analog filter characteristics⁽¹⁾

Symbol	Parameter	Min	Max	Unit
t_{SP}	Pulse width of spikes that are suppressed by the analog filter	50	260	ns

1. Guaranteed by design, not tested in production.

Figure 23. I²C bus AC waveforms and measurement circuit

1. Measurement points are done at CMOS levels: $0.3V_{DD}$ and $0.7V_{DD}$.

Figure 32. USB timings: definition of data signal rise and fall time**Table 73. USB: Full-speed electrical characteristics⁽¹⁾**

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Driver characteristics						
t_r	Rise time ⁽²⁾	$C_L = 50 \text{ pF}$	4	-	20	ns
t_f	Fall time ⁽²⁾	$C_L = 50 \text{ pF}$	4	-	20	ns
t_{rfm}	Rise/ fall time matching	t_r/t_f	90	-	110	%
V_{CRS}	Output signal crossover voltage		1.3	-	2.0	V
Output driver Impedance ⁽³⁾	Z_{DRV}	driving high and low	28	40	44	Ω

1. Guaranteed by design, not tested in production.
2. Measured from 10% to 90% of the data signal. For more detailed informations, please refer to USB Specification - Chapter 7 (version 2.0).
3. No external termination series resistors are required on USB_DP (D+) and USB_DM (D-), the matching impedance is already included in the embedded driver.

6.3.24 CAN (controller area network) interface

Refer to [Section 6.3.14: I/O port characteristics](#) for more details on the input/output alternate function characteristics (CAN_TX and CAN_RX).

6.3.25 SDADC characteristics

Table 74. SDADC characteristics ⁽¹⁾

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	Note
V_{DDSDx}	Power supply	Slow mode ($f_{ADC} = 1.5 \text{ MHz}$)	2.2		V_{DDA}	V	
		Fast mode ($f_{ADC} = 6 \text{ MHz}$)	2.4		V_{DDA}		
f_{ADC}	SDADC clock frequency	Slow mode ($f_{ADC} = 1.5 \text{ MHz}$)	0.5	1.5	1.65	MHz	
		Fast mode ($f_{ADC} = 6 \text{ MHz}$)	0.5	6	6.3		
V_{REFSD+}	Positive ref. voltage		1.1		V_{DDSDx}	V	
V_{REFSD-}	Negative ref. voltage			V_{SSA}		V	

7 Package characteristics

7.1 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

SEATING PLANE
C

A
A2
A1
c

ccc C

0.25 mm
GAUGE PLANE

A1
L
L1
A

D
D1
D3

75
51
76
50
E3
E1
E

b

100
1
25
26

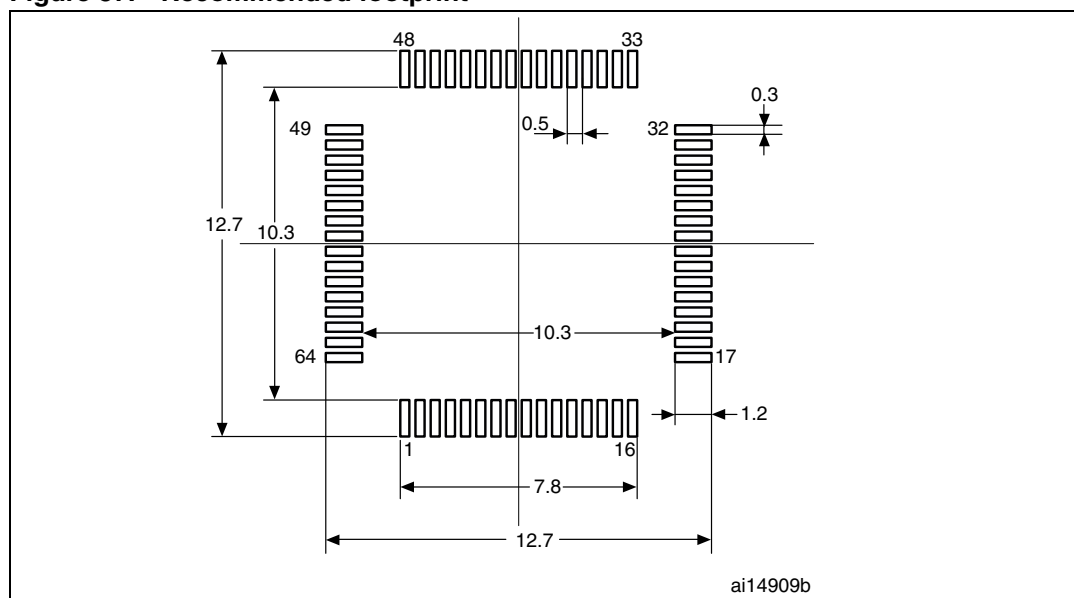
PIN 1
IDENTIFICATION

e

Symbol	millimeters			inches ⁽¹⁾		
	Min	Typ	Max	Min	Typ	Max
A			1.60			0.063
A1	0.05		0.15	0.002		0.0059
A2	1.35	1.40	1.45	0.0531	0.0551	0.0571
b	0.17	0.22	0.27	0.0067	0.0087	0.0106
c	0.09		0.20	0.0035		0.0079
D	15.80	16.00	16.20	0.622	0.6299	0.6378
D1	13.80	14.00	14.20	0.5433	0.5512	0.5591
D3		12.00			0.4724	
E	15.80	16.00	16.20	0.622	0.6299	0.6378

Symbol	millimeters			inches ⁽¹⁾		
	Min	Typ	Max	Min	Typ	Max
E	11.80	12.00	12.20	0.4646	0.4724	0.4803
E1	9.80	10.00	10.20	0.3858	0.3937	0.4016
E3		7.50			0.2953	
e		0.50			0.0197	
L	0.45	0.60	0.75	0.0177	0.0236	0.0295
L1		1.00			0.0394	
K	0°	3.5°	7°	0°	3.5°	7°
ccc			0.08			0.0031

Figure 37. Recommended footprint



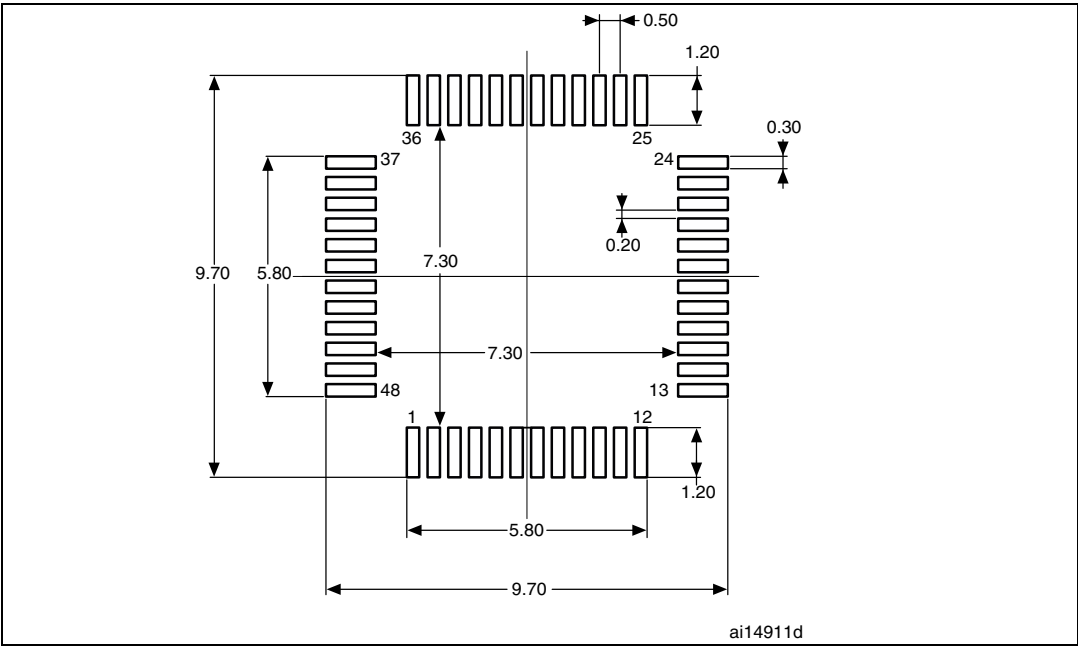
1. Dimensions are in millimeters.

Table 79. LQFP48 – 7 x 7 mm, low-profile quad flat package mechanical data (continued)

Symbol	millimeters			inches ⁽¹⁾		
	Min	Typ	Max	Min	Typ	Max
e		0.50			0.0197	
L	0.45	0.60	0.75	0.0177	0.0236	0.0295
L1		1.00			0.0394	
K	0°	3.5°	7°	0°	3.5°	7°
ccc			0.08			0.0031

1. Values in inches are converted from mm and rounded to 4 decimal digits.

Figure 39. Recommended footprint



1. Dimensions are in millimeters.

7.2 Thermal characteristics

The maximum chip junction temperature (T_{Jmax}) must never exceed the values given in [Table 22: General operating conditions on page 55](#).

The maximum chip-junction temperature, T_J max, in degrees Celsius, may be calculated using the following equation:

$$T_J \text{ max} = T_A \text{ max} + (P_D \text{ max} \times \Theta_{JA})$$

Where:

- T_A max is the maximum ambient temperature in °C,
- Θ_{JA} is the package junction-to-ambient thermal resistance, in °C/W,
- P_D max is the sum of P_{INT} max and $P_{I/O}$ max ($P_D \text{ max} = P_{INT} \text{ max} + P_{I/O} \text{ max}$),
- P_{INT} max is the product of I_{DD} and V_{DD} , expressed in Watts. This is the maximum chip internal power.

$P_{I/O}$ max represents the maximum power dissipation on output pins where:

$$P_{I/O} \text{ max} = \Sigma (V_{OL} \times I_{OL}) + \Sigma ((V_{DD} - V_{OH}) \times I_{OH}),$$

taking into account the actual V_{OL} / I_{OL} and V_{OH} / I_{OH} of the I/Os at low and high level in the application.

Table 80. Package thermal characteristics

Symbol	Parameter	Value	Unit
Θ_{JA}	Thermal resistance junction-ambient LQFP64 - 10 × 10 mm / 0.5 mm pitch	45	°C/W
	Thermal resistance junction-ambient LQFP48 - 7 × 7 mm	55	
	Thermal resistance junction-ambient LQFP100 - 14 × 14 mm / 0.5 mm pitch	46	
	Thermal resistance junction-ambient BGA100 - 7 × 7 mm	59	

7.2.1 Reference document

JESD51-2 Integrated Circuits Thermal Test Method Environment Conditions - Natural Convection (Still Air). Available from www.jedec.org